



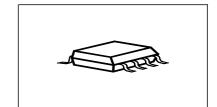


Features

- Logic Level Input
- Input Protection (ESD)
- Thermal shutdown with auto restart
- Green product (RoHS compliant)
- Overload protection
- Short circuit protection
- Overvoltage protection
- Current limitation
- Analog driving possible

Product Summary

Drain source voltage	V_{DS}	42	٧
On-state resistance	R _{DS(on)}	200	mΩ
Nominal load current	I _{D(Nom)}	1.3	Α
Clamping energy	E _{AS}	150	mJ

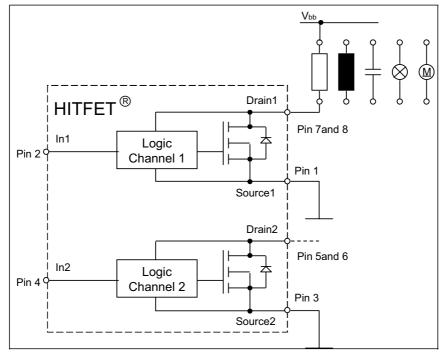


Application

- All kinds of resistive, inductive and capacitive loads in switching or linear applications
- µC compatible power switch for 12 V DC applications
- Replaces electromechanical relays and discrete circuits

General Description

N channel vertical power FET in Smart SIPMOS® technology. Fully protected by embedded protection functions.



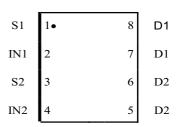
Complete product spectrum and additional information http://www.infineon.com/hitfet



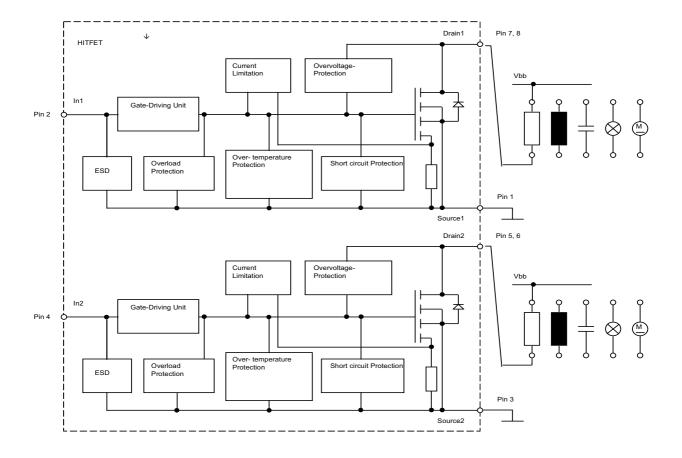
Pin Description

Pin	Symbol	Function	
1	S1	Source Channel 1	
2	IN1	Input Channel 1	
3	S2	Source Channel 2	
4	IN2	Input Channel 2	
5	D2	Drain Channel 2	
6	D2	Drain Channel 2	
7	D1	Drain Channel 1	
8	D1	Drain Channel 1	

Pin Configuration (Top view)



PG-DSO-8-25



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Maximum Ratings at T_i = 25°C, unless otherwise specified

Parameter	Symbol	Value	Unit	
Drain source voltage	V_{DS}	42	V	
Drain source voltage for short circuit protection 1)	V _{DS(SC)}	18		
<i>T</i> _j = -40150 °C	, ,			
Continuous input current ¹⁾	/ _{IN}		mA	
$-0.2V \le V_{IN} \le 10V$		no limit		
V_{IN} < -0.2V or V_{IN} > 10V		$ I_{1N} \le 2$		
Operating temperature	T_{i}	-40+150	°C	
Storage temperature	$T_{\rm stg}$	-55 + 150		
Power dissipation ²⁾⁵⁾	P _{tot}	0.8	W	
<i>T</i> _A = 85 °C				
Unclamped single pulse inductive energy ¹⁾	E _{AS}	150	mJ	
each channel				
Load dump protection $V_{\text{LoadDump}}^{(1)3)} = V_{\text{A}} + V_{\text{S}}$	V_{LD}	50	V	
$V_{\rm IN}$ = 0 and 10 V, $t_{\rm d}$ = 400 ms, $R_{\rm I}$ = 2 Ω ,				
$R_{L} = 9 \Omega, V_{A} = 13.5 V$				
Electrostatic discharge voltage1) (Human Body Model)	V _{ESD}	2	kV	
according to Jedec norm				
EIA/JESD22-A114-B, Section 4				

Thermal resistance

junction - ambient: per channel		R _{thJA}		K/W
@ 6 cm ² cooling area ²⁾	one channel on		100	
	both channels on		160	

¹not subject to production test, specified by design

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² Device on 50mm*50mm*1.5mm epoxy PCB FR4 with 6cm² (one layer, 70μm thick) copper area for drain connection. PCB mounted vertical without blown air.

 $^{^3}V_{
m Loaddump}$ is setup without the DUT connected to the generator per ISO 7637-1 and DIN 40839

 $^{^{5}}$ not subject to production test, calculated by $\rm R_{THJA}$ and $\rm R_{ds(on)}$



Electrical Characteristics

Parameter	Symbol Values		Unit		
at T_j = 25°C, unless otherwise specified		min.	typ.	max.	
Characteristics					
Drain source clamp voltage	$V_{\rm DS(AZ)}$	42	-	55	V
$T_{\rm j}$ = -40+ 150, $I_{\rm D}$ = 10 mA					
Off-state drain current T _j = -40 +150°C	I _{DSS}	-	1.5	10	μΑ
$V_{\rm DS} = 32 \text{ V}, \ V_{\rm IN} = 0 \text{ V}$					
Input threshold voltage	$V_{\rm IN(th)}$				V
$I_{\rm D}$ = 0.3 mA, $T_{\rm j}$ = 25 °C		1.3	1.7	2.2	
$I_{\rm D}$ = 0.3 mA, $T_{\rm j}$ = 150 °C		0.8	-	-	
On state input current	I _{IN(on)}	-	10	30	μΑ
On-state resistance	R _{DS(on)}				mΩ
$V_{\rm IN}$ = 5 V, $I_{\rm D}$ = 1.4 A, $T_{\rm j}$ = 25 °C		-	190	240	
$V_{\rm IN}$ = 5 V, $I_{\rm D}$ = 1.4 A, $T_{\rm j}$ = 150 °C		-	350	480	
On-state resistance	R _{DS(on)}				
$V_{\rm IN}$ = 10 V, $I_{\rm D}$ = 1.4 A, $T_{\rm j}$ = 25 °C		-	150	200	
$V_{\rm IN}$ = 10 V, $I_{\rm D}$ = 1.4 A, $T_{\rm j}$ = 150 °C		-	280	400	
Nominal load current per channel ⁵⁾	I _{D(Nom)}				Α
$V_{\rm DS}$ = 0.5 V, $T_{\rm j}$ < 150°C, $V_{\rm IN}$ = 10 V, $T_{\rm A}$ = 85 °C,					
one channel on		1.3	1.65	_	
both channels on		1	1.3	_	
Current limit (active if V _{DS} >2.5 V) ²⁾	I _{D(lim)}	5	7.5	10	1
$V_{\rm IN}$ = 10 V, $V_{\rm DS}$ = 12 V, $t_{\rm m}$ = 200 $\mu {\rm s}$					

¹not subject to production test, specified by design

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²Device switched on into existing short circuit (see diagram Determination of $b_{(lim)}$). If the device is in on conc and a short circuit occurs, these values might be exceeded for max. 50 μ s.

 $^{^{5}}$ not subject to production test, calculated by $R_{\mbox{\scriptsize THJA}}$ and $R_{\mbox{\scriptsize ds(on)}}$



Electrical Characteristics

Parameter	Symbol	Values			Unit	
at T_j = 25°C, unless otherwise specified	specified		typ.	max.	<u> </u>	
Dynamic Characteristics						
Turn-on time V_{IN} to 90% I_{D} :	<i>t</i> on	1	45	100	μs	
$R_{\rm L}$ = 4.7 Ω , $V_{\rm IN}$ = 0 to 10 V, $V_{\rm bb}$ = 12 V						
Turn-off time V_{IN} to 10% I_{D} :	$t_{ m off}$	-	60	100		
$R_{\rm L}$ = 4.7 Ω , $V_{\rm IN}$ = 10 to 0 V, $V_{\rm bb}$ = 12 V						
Slew rate on 70 to 50% $V_{\rm bb}$:	-dV _{DS} /dt _{on}	-	0.4	1.5	V/µs	
$R_{\rm L}$ = 4.7 Ω , $V_{\rm IN}$ = 0 to 10 V, $V_{\rm bb}$ = 12 V						
Slew rate off 50 to 70% $V_{\rm bb}$:	dV _{DS} /dt _{off}	-	0.6	1.5		
$R_{\rm L}$ = 4.7 Ω , $V_{\rm IN}$ = 10 to 0 V, $V_{\rm bb}$ = 12 V						
Protection Functions ¹⁾						
Thermal overload trip temperature	$T_{\rm jt}$	150	175	-	°C	
Thermal hysteresis ²⁾	$\Delta T_{ m jt}$	-	10	-	K	
Input current protection mode	I _{IN(Prot)}	25	50	300	μΑ	
Input current protection mode	I _{IN(Prot)}	-	- 40 300			
<i>T</i> _j = 150 °C						
Unclamped single pulse inductive energy ²⁾	E _{AS}	150	-	-	mJ	
each channel						
$I_D = 0.9 \text{ A}, T_j = 25 \text{ °C}, V_{bb} = 12 \text{ V}$						
Inverse Diode						
Inverse diode forward voltage	V_{SD}	-	1	-	V	
I_{F} = 7 A, t_{m} = 250 µs, V_{IN} = 0 V,						
$t_{\rm P}$ = 300 µs						

¹Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation

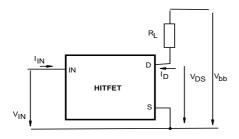
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²not subject to production test, specified by design

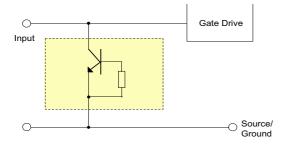


Block diagram

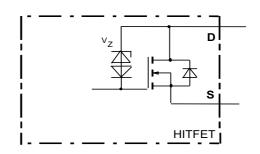
Terms



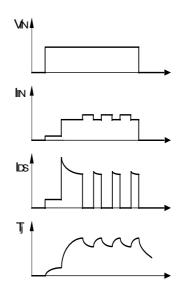
Input circuit (ESD protection)



Inductive and overvoltage output clamp



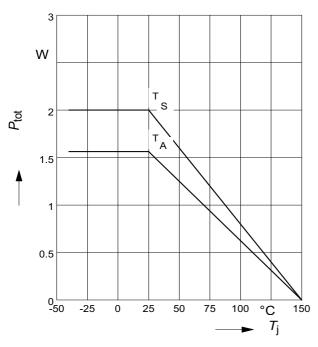
Short circuit behaviour





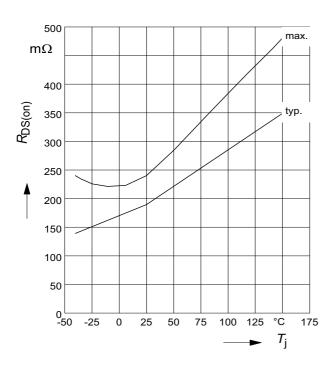
1 Overall maximum allowable power dissipation; $P_{tot} = f(T_S)$ resp.

$$P_{tot} = f(T_A) @ R_{thJA} = 80 \text{ K/W}$$



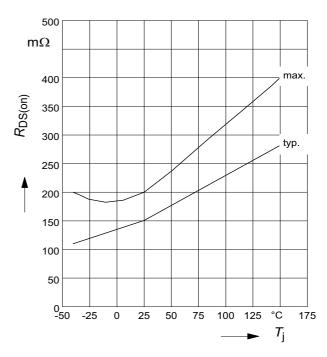
3 On-state resistance

$$R_{ON} = f(T_i); I_D = 1.4A; V_{IN} = 5V$$



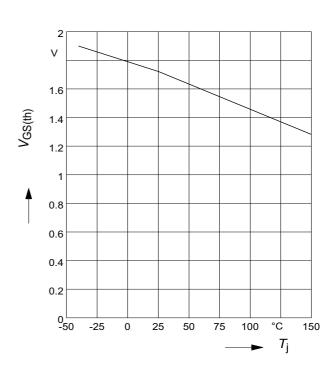
2 On-state resistance

$$R_{ON} = f(T_j); I_D = 1.4A; V_{IN} = 10V$$



4 Typ. input threshold voltage

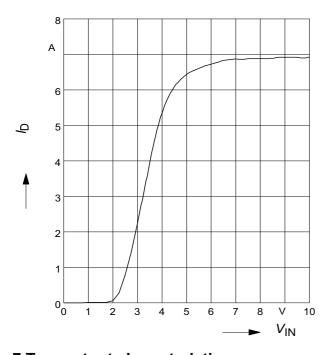
$$V_{IN(th)} = f(T_j); I_D = 0.15 \text{ mA}; V_{DS} = 12V$$





5 Typ. transfer characteristics

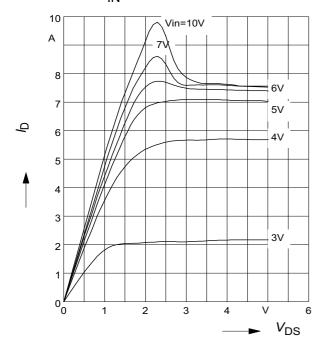
 I_D = $f(V_{IN})$; V_{DS} =12V; T_{Jstart} =25 $^{\circ}$ C



7 Typ. output characteristics

I_D=f(V_{DS}); T_{Jstart}=25°C

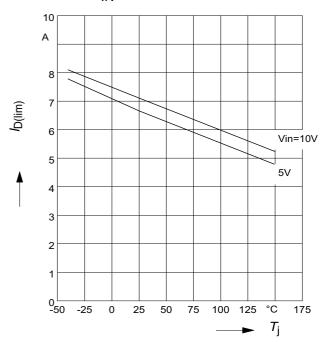
Parameter: V_{IN}



6 Typ. short circuit current

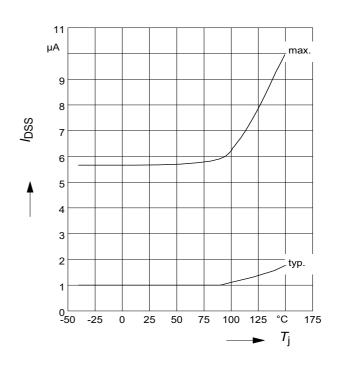
 $I_{D(lim)} = f(Tj); V_{DS} = 12V$

Parameter: V_{IN}



8 Typ. off-state drain current

 $I_{\text{DSS}} = f(T_{j})$

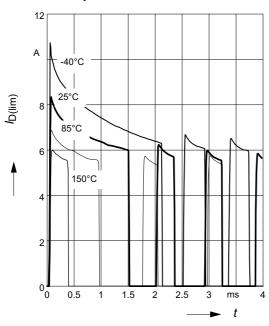




9 Typ. overload current

 $I_{D(lim)} = f(t)$, $V_{bb} = 12$ V, no heatsink

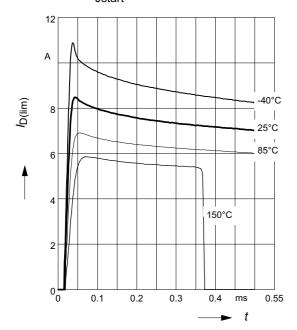
Parameter: T_{jstart}



11 Determination of I_{D(lim)}

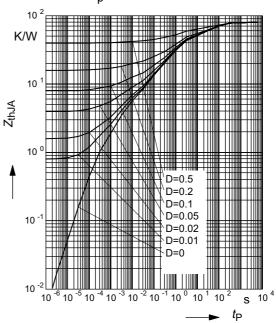
 $I_{D(lim)} = f(t); t_m = 200 \mu s$

Parameter: T_{Jstart}



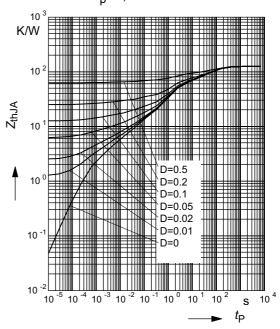
10 Typ. transient thermal impedance $Z_{\text{thJA}} = f(t_{\text{p}}) @ 6 \text{ cm}^2 \text{ cooling area}$

Parameter: $D=t_p/T$; one channel on



12 Typ. transient thermal impedance $Z_{\text{thJA}} = f(t_{\text{p}}) @ 6 \text{ cm}^2 \text{ cooling area}$

Parameter: $D=t_p/T$; both channels on





Package Outlines

1 Package Outlines

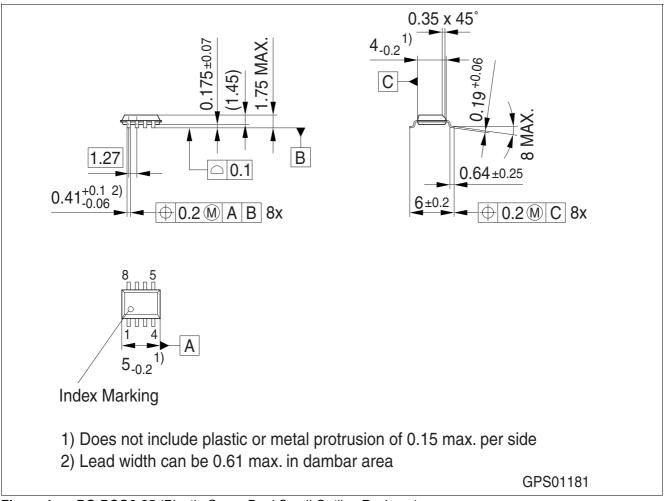


Figure 1 PG-DSO8-25 (Plastic Green Dual Small Outline Package)

Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

Please specify the package needed (e.g. green package) when placing an order

For further information on alternative packages, please visit our website: http://www.infineon.com/packages.

Dimensions in mm



Revision History

2 Revision History

Version	Date	Changes
Rev. 1.3	2007-11-06	updated package drawing of green package
Rev. 1.2	2007-06-18	released automotive green version Package parameter (humidity and climatic) removed in Maximum ratings AEC icon added RoHS icon added Green product (RoHS-compliant) added to the feature list Package information updated to green package naming Green explanation added
Rev. 1.1	2004-03-05	released production version

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Edition 2007-11-06

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